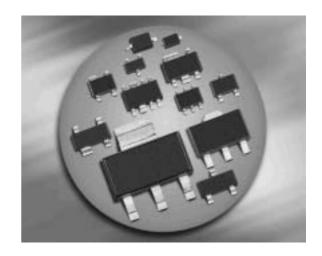


## **Silicon Variable Capacitance Diode**

- For Hyperband TV / VTR tuners, Bd I
- Large capacitance ratio, low series resistance
- Pb-free (RoHS compliant) package 1)
- Qualified according AEC Q101





#### **SD199**



Туре	Package	Configuration	<b>L</b> S(nH)	Marking
SD199E6327	SOD323	single	1.8	red S

## **Maximum Ratings** at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_{R}$	30	V
Peak reverse voltage-	$V_{RM}$	35	
Forward current	I <sub>F</sub>	20	mA
Operating temperature range	$T_{op}$	-55 150	°C
Storage temperature	$T_{ m stg}$	-55 150	

<sup>&</sup>lt;sup>1</sup>Pb-containing package may be available upon special request

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## **Electrical Characteristics** at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit	
		min.	typ.	max.		
DC Characteristics						
Reverse current	I <sub>R</sub>				nA	
$V_{R} = 30 \text{ V}$		-	-	10		
$V_{R} = 30 \text{ V}, T_{A} = 85$		-	-	200		
AC Characteristics						
Diode capacitance	C <sub>T</sub>				pF	
$V_{R} = 1 \text{ V}, f = 1 \text{ MHz}$		62	69	76		
$V_{R} = 2 \text{ V}, f = 1 \text{ MHz}$		47	54	62		
$V_{R} = 25 \text{ V}, f = 1 \text{ MHz}$		2.85	3.18	3.6		
$V_{R} = 28 \text{ V}, f = 1 \text{ MHz}$		2.8	3.05	3.3		
Capacitance ratio	C <sub>T1</sub> /C <sub>T28</sub>	19.5	22.6	25	-	
$V_{R} = 1 \text{ V}, V_{R} = 28 \text{ V}, f = 1 \text{ MHz}$						
Capacitance ratio	$C_{T2}/C_{T25}$	15	17	19		
$V_{R} = 2 \text{ V}, V_{R} = 25 \text{ V}, f = 1 \text{ MHz}$						
Capacitance matching <sup>1)</sup>	$\Delta C_{T}/C_{T}$	-	-	2.5	%	
$V_R = 1 \dots 28 \text{ V}, f = 1 \text{ MHz}, 8 \text{ diodes sequence}$						
Series resistance	r <sub>S</sub>	-	1.15	-	Ω	
$V_{R} = 5 \text{ V}, f = 470 \text{ MHz}$						

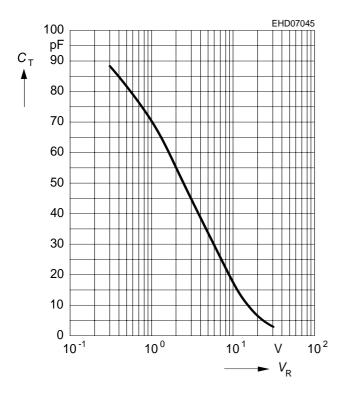
<sup>&</sup>lt;sup>1</sup>For details please refer to Application Note 047.

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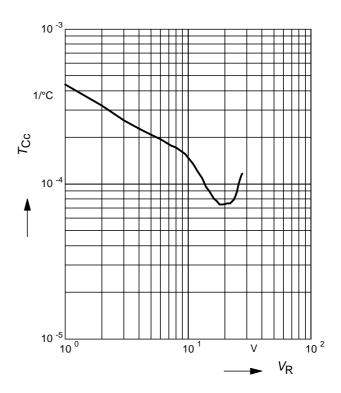


## **Diode capacitance** $C_T = f(V_R)$

f = 1MHz

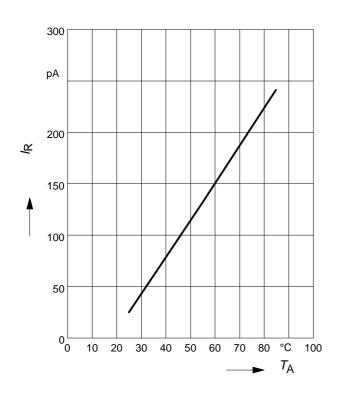


# Temperature coefficient of the diode capacitance $T_{Cc} = f(V_R)$



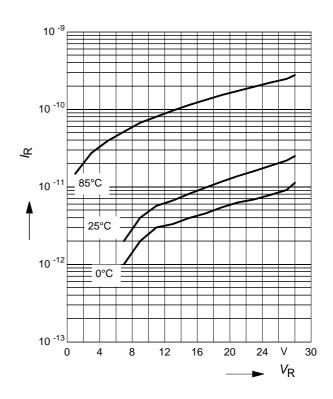
## Reverse current $I_R = f(T_A)$

 $V_{R} = 28 \text{ V}$ 



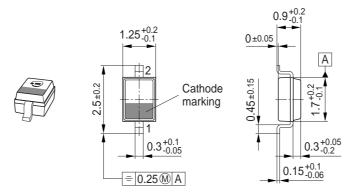
## Reverse current $I_R = f(V_R)$

 $T_A$  = Parameter

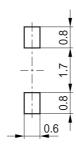




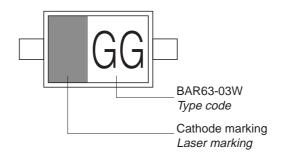
## Package Outline



## Foot Print

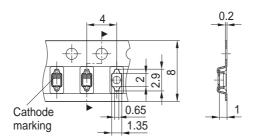


## Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



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